

/ Descriptions

SOT-23 NPN Silicon NPN transistor in a SOT-23 Plastic Package.

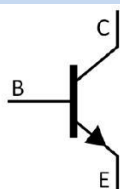
/ Features

, , h_{FE} ,
High voltage and high current, excellent h_{FE} linearity ,low noise.

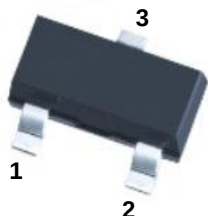
/ Applications

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Audio frequency general purpose, driver stage amplifier applications.

/ Equivalent Circuit



/ Pinning



PIN1 Base PIN 2 Emitter PIN 3 Collector

/ h_{FE} Classifications & Marking

h_{FE} Classifications Symbol	O	Y	GR	BL
h_{FE} Range	70 140	120 240	200 400	350 700
Marking	HHFO	HHFY	HHFG	HHFB

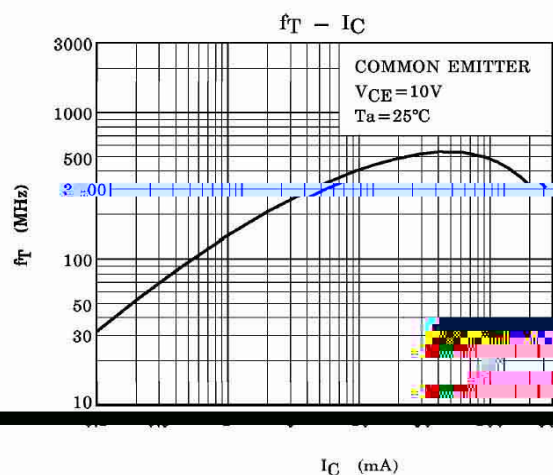
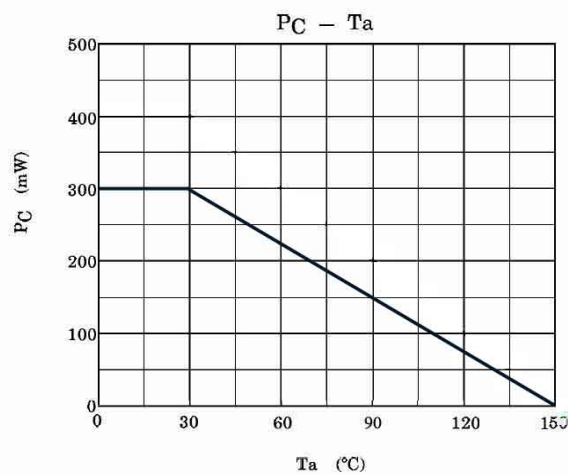
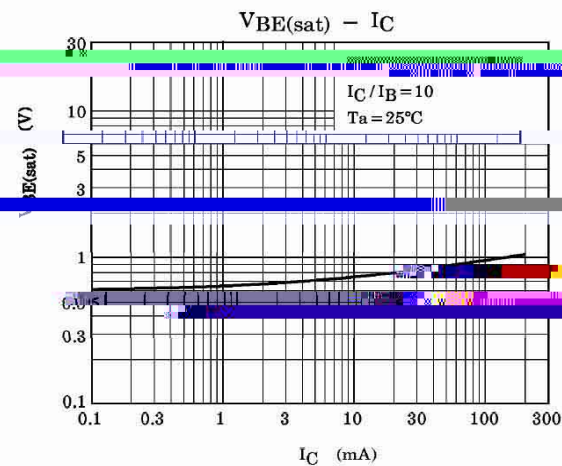
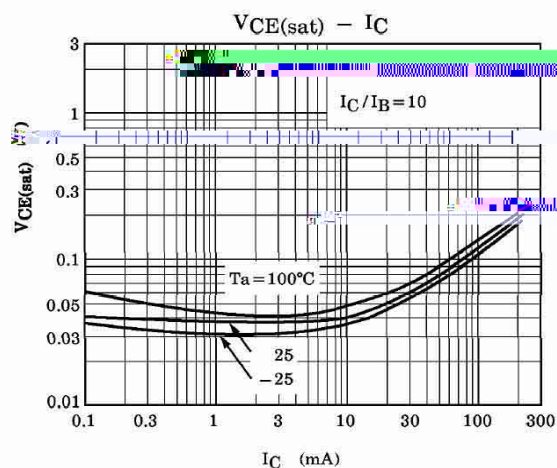
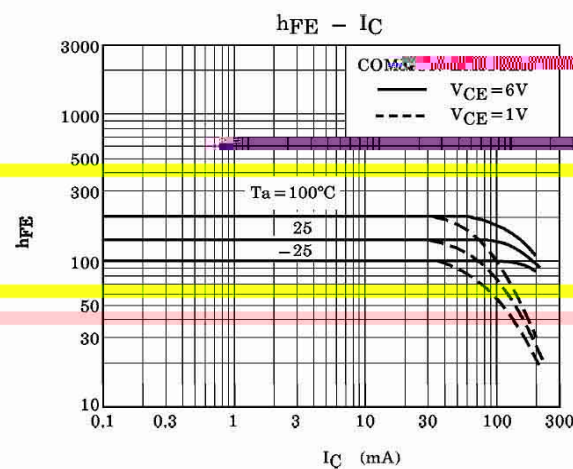
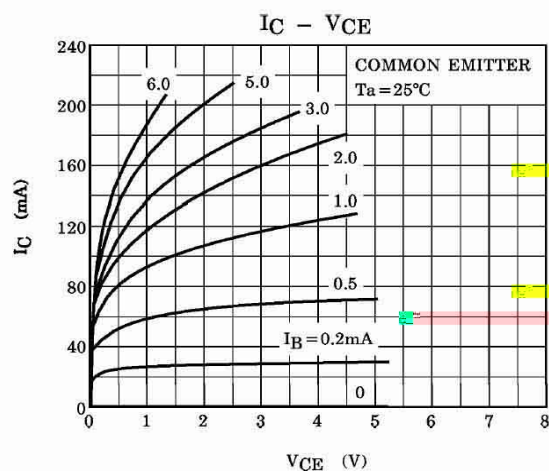
/ Absolute Maximum Ratings(Ta=25)

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	60	V
Collector to Emitter Voltage	V_{CEO}	50	V
Emitter to Base Voltage	V_{EBO}	5.0	V
Collector Current	I_C	150	mA
Base Current	I_B	50	mA
Collector Power Dissipation	P_C	300	mW
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	

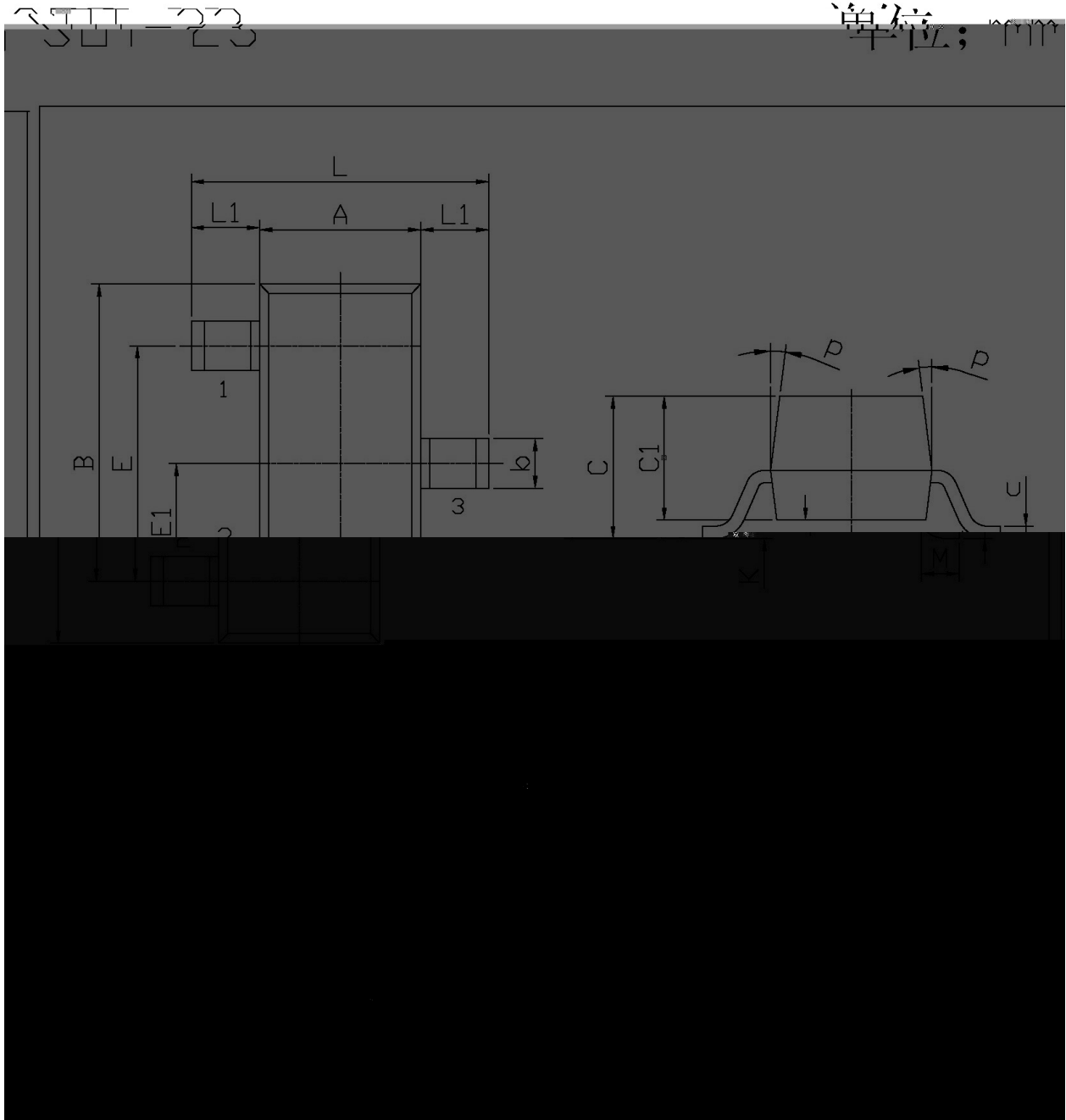
/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector Cut-Off Current	I_{CBO}	$V_{CB}=60V$ $I_E=0$			0.1	A
Emitter Base Cut-Off Current	I_{EBO}	$V_{EB}=5.0V$ $I_C=0$			0.1	A
DC Current Gain	$h_{FE(1)}$	$V_{CE}=6.0V$ $I_C=2.0mA$	70		700	
	$h_{FE(2)}$	$V_{CE}=6.0V$ $I_C=150mA$	25	100		
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=100mA$ $I_B=10mA$		0.1	0.25	V
Base to Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=100mA$ $I_B=10mA$			1.0	V
Transition Frequency	f_T	$V_{CE}=10V$ $I_C=1.0mA$	80			MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=10V$ $f=1.0MHz$ $I_E=0$		2.0	3.5	pF
Base Intrinsic Resistance	$r_{bb'}$	$V_{CB}=10V$ $f=30MHz$ $I_C=1.0mA$		50		
Noise Figure	NF	$V_{CE}=6.0V$ $R_g=10K$ $I_C=0.1mA$ $f=1.0KHz$		1.0	10	dB

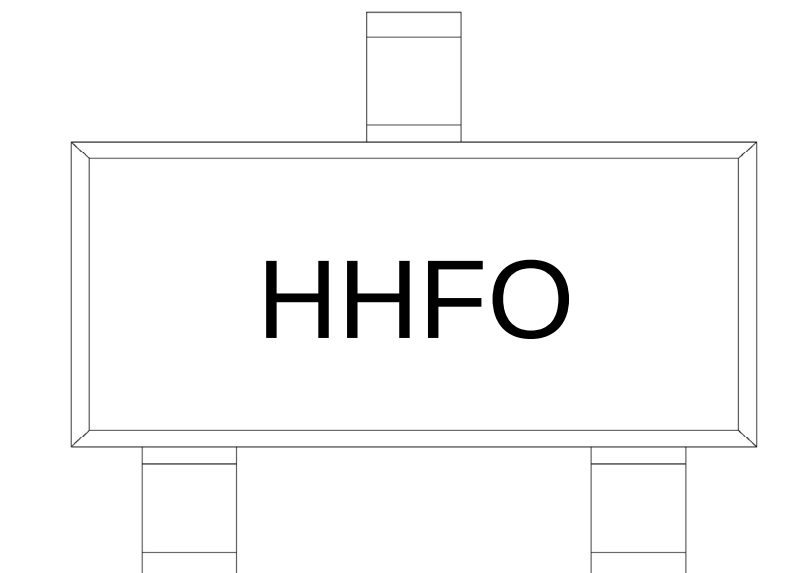
/ Electrical Characteristic Curve



/ Package Dimensions



/ Marking Instructions



H

HF

O: h_{FE}

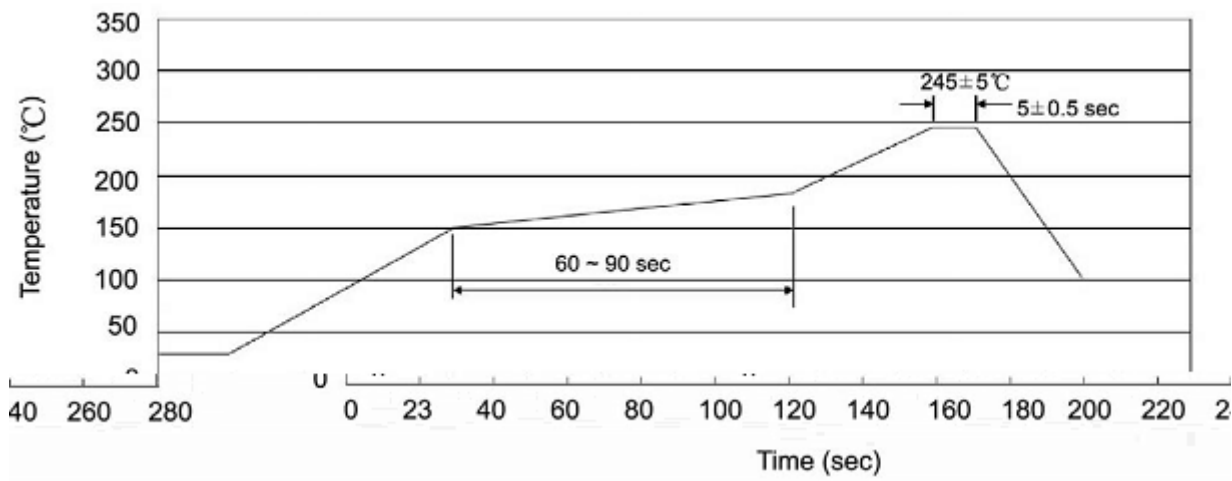
Note:

H: Company Code

HF: Product Type Code

O: h_{FE} Classifications Symbol Code

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Note:

- | | | | | | |
|---|----|-------|----|-----------|---|
| 1 | 25 | 150 | 60 | 90sec; | 1.Preheating:25~150 , Time:60~90sec. |
| 2 | | 245±5 | | 5±0.5sec; | 2.Peak Temp.:245±5 , Duration:5±0.5sec. |
| 3 | | | 2 | 10 /sec. | 3. Cooling Speed: 2~10 /sec. |

/ Resistance to Soldering Heat Test Conditions

260±5	10±1 sec.	Temp.:260±5	Time:10±1 sec
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